

5N60K-MTQ Preliminary Power MOSFET

5A, 600V N-CHANNEL POWER MOSFET

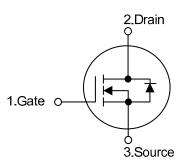
■ DESCRIPTION

The UTC **5N60K-MTQ** is a high voltage power MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and have a high rugged avalanche characteristics. This power MOSFET is usually used at high speed switching applications in power supplies, PWM motor controls, high efficient DC to DC converters and bridge circuits.

■ FEATURES

- * $R_{DS(ON)}$ < 2.2 Ω @ V_{GS} =10V, I_D = 2.5A
- * Fast Switching Capability
- * Avalanche Energy Specified
- * Improved dv/dt Capability, High Ruggedness

■ SYMBOL

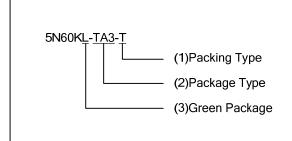


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■ ORDERING INFORMATION

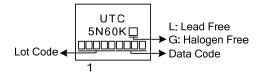
Ordering Number		Package	Pin	Dooking			
Lead Free	Halogen Free	Fackage	1	2	3	Packing	
5N60KL-TA3-T	5N60KG-TA3-T	TO-220	G	D	S	Tube	
5N60KL-TF1-T	5N60KG-TF1-T	TO-220F1	G	D	S	Tube	
5N60KL-TF2-T	5N60KG-TF2-T	TO-220F2	G	D	S	Tube	
5N60KL-TF3-T	5N60KG-TF3-T	TO-220F	G	D	S	Tube	
5N60KL-TF3T-T	5N60KG-TF3T-T	TO-220F3	G	D	S	Tube	
5N60KL-TM3-T	5N60KG-TM3-T	TO-251	G	D	S	Tube	
5N60KL-TMS-T	5N60KG-TMS-T	TO-251S	G	D	S	Tube	
5N60KL-TMS2-T	5N60KG-TMS2-T	TO-251S2	G	D	S	Tube	
5N60KL-TMS4-T	5N60KG-TMS4-T	TO-251S4	G	D	S	Tube	
5N60KL-TN3-R	5N60KG-TN3-R	TO-252	G	D	S	Tape Reel	
5N60KL-TND-R	5N60KG-TND-R	TO-252D	G	D	S	Tape Reel	
5N60KL-T2Q-T	5N60KG-T2Q-T	TO-262	G	D	S	Tube	

Note: Pin Assignment: G: Gate D: Drain S: Source



- (1) T: Tube, R: Tape Reel
- (2) TA3: TO-220, TF1: TO-220F1, TF2: TO-220F2 TF3: TO-220F, TF3T: TO-220F3, TM3: TO-251, TMS: TO-251S, TMS2: TO-251S2, TN3: TO-252, TMS4: TO-251S4, TND: TO-252D, T2Q: TO-262,
- (3) L: Lead Free, G: Halogen Free and Lead Free

■ MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_C = 25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	600	V
Gate-Source Voltage		V_{GSS}	±30	V
Continuous Drain Current		I _D	5	Α
Pulsed Drain Current (Note 2)		I _{DM}	20	Α
Avalanche Energy	Single Pulsed (Note 3)	E _{AS}	220	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	4.5	V/ns
Power Dissipation	TO-220/TO-262		100	W
	TO-220F/TO-220F1 TO-220F3		36	W
	TO-220F2	P_{D}	38	W
	TO-251/ TO-251S TO-251S2/TO-251S4 TO-252/TO-252D		54	W
Junction Temperature		T_J	+150	°C
Operation Temperature		T _{OPR}	-55 ~ +150	°C
Storage Temperature		T_{STG}	-55 ~ + 150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Pulse width limited by $T_{J(MAX)}$
- 3. L = 17.6mH, I_{AS} = 5A, V_{DD} = 50V, R_{G} = 25 Ω , Starting T_{J} = 25°C
- 4. $I_{SD} \le 5A$, di/dt $\le 200A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25^{\circ}C$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220/TO-262 TO-220F/TO-220F1 TO-220F2/TO-220F3	0	62.5	°C/W
	TO-251/ TO-251S TO-251S2/TO-251S4 TO-252/TO-252D	θ _{JA}	160	°C/W
Junction to Case	TO-220/TO-262		1.25	°C/W
	TO-220F/TO-220F1 TO-220F3		3.47	°C/W
	TO-220F2	θ_{JC}	3.28	°C/W
	TO-251/ TO-251S TO-251S2/TO-251S4 TO-252/TO-252D		2.30	°C/W

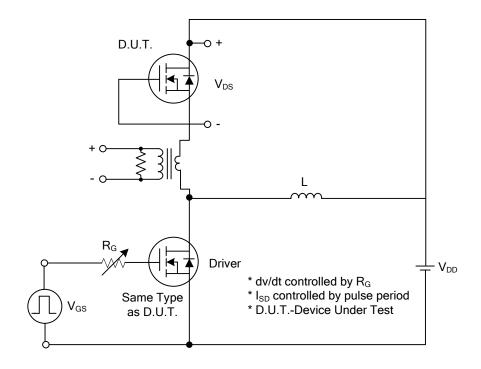
■ **ELECTRICAL CHARACTERISTICS** (T_C = 25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS				•	•		
Drain-Source Breakdown Voltage		BV _{DSS}	V _{GS} =0V, I _D = 250μA	600			V
Drain-Source Leakage Current		I _{DSS}	V _{DS} =600V, V _{GS} = 0V			1	μA
Gate-Source Leakage Current	Forward		V_{GS} =30V, V_{DS} = 0V			100	- A
	Reverse	I _{GSS}	$V_{GS} = -30V, V_{DS} = 0V$			-100	nA
Breakdown Voltage Temperature Coefficient		$\triangle BV_{DSS}/\triangle T_{J}$	I _D =250μA, Referenced to 25°C		0.6		V/°C
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0		4.0	٧
Static Drain-Source On-State Resistance		R _{DS(ON)}	$V_{GS} = 10V, I_D = 2.5A$		1.8	2.2	Ω
DYNAMIC CHARACTERISTICS							
Input Capacitance		C _{ISS}	V = 25V V = 0V		520	620	pF
Output Capacitance		Coss	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1.0MHz		65	90	pF
Reverse Transfer Capacitance		C_{RSS}	1 - 1.0WH2		8	12	pF
SWITCHING CHARACTERISTIC	S						
Turn-On Delay Time		$t_{D(ON)}$			50		ns
Turn-On Rise Time		t_R	V_{DD} =30V, I_{D} =0.5A, R_{G} =25 Ω		55		ns
Turn-Off Delay Time		$t_{D(OFF)}$	(Note 1, 2)		87		ns
Turn-Off Fall Time		t_{F}			40		ns
Total Gate Charge		Q_G	V -50V I -4 2A V -40V		25		nC
Gate-Source Charge		Q_GS	V _{DS} =50V, I _D =1.3A, V _{GS} =10V (Note 1, 2)		5.5		nC
Gate-Drain Charge		Q_GD	(Note 1, 2)		4.5		nC
DRAIN-SOURCE DIODE CHARA	CTERISTIC	CS AND MAXII	MUM RATINGS				
Drain-Source Diode Forward Volta	age	V_{SD}	$V_{GS} = 0 \text{ V}, I_{S} = 5A$			1.4	V
Maximum Continuous Drain-Source Diode Forward Current		Is				5	Α
						υ	A
Maximum Pulsed Drain-Source Diode		I _{SM}				20	Α
Forward Current						20	^

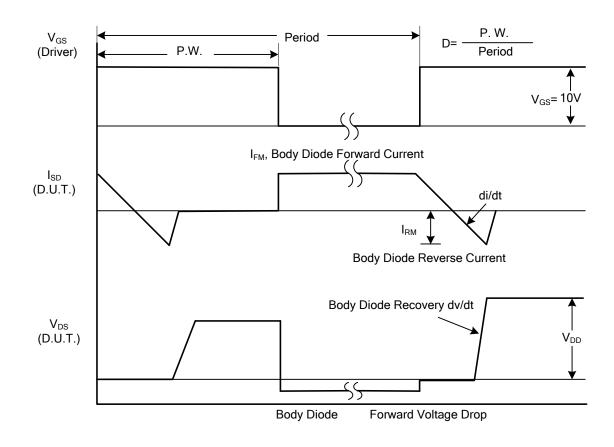
Note: 1. Pulse Test: Pulse width ≤ 300µs, Duty cycle ≤ 2%

^{2.} Essentially independent of operating temperature

■ TEST CIRCUITS AND WAVEFORMS

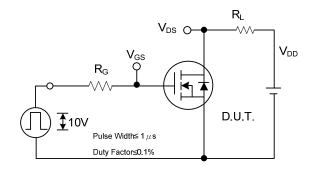


Peak Diode Recovery dv/dt Test Circuit

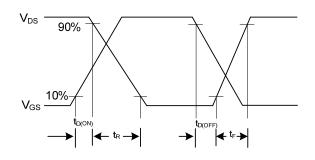


Peak Diode Recovery dv/dt Waveforms

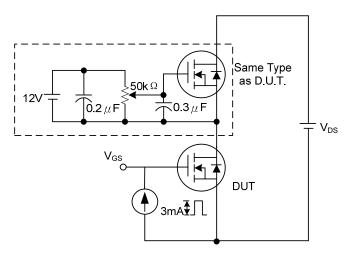
■ TEST CIRCUITS AND WAVEFORMS (Cont.)



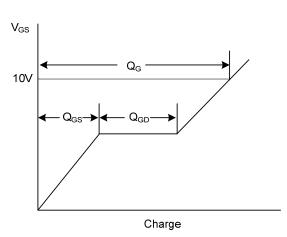
Switching Test Circuit



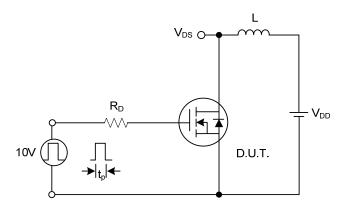
Switching Waveforms



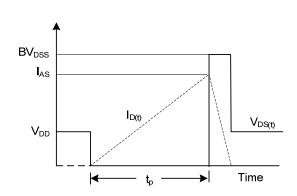
Gate Charge Test Circuit



Gate Charge Waveform



Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms

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